

Serial No. : 2023-0385 DATE: 2023/6/19

\_\_\_\_\_

# **SPECIFICATION**

Product Name	CRYSTAL OSCILLATOR	
Туре	DSO221SXF	
Nominal Frequency	22.5792MHz	
Spec No.	7FE02257A0C	

If there is a change in this specifications, the specification number may be changed.

	RECEIPT	
DATE		
RECEIVED		(signature) (name)

General Manufacturer of Quartz Devices

# DAISHINKU CORP.

1389 Shinzaike, Hiraoka-cho, Kakogawa, Hyogo 675-0194 Japan

Phone: (81)79-425-3161 Fax.:(81)79-425-1134 http://www.kds.info/index\_en.htm

C.ENG.

y. Momoo

ENG.

A Vanto

**1. Device name** SPXO (Output specification C-MOS)

**2. Type name** DSO221SXF

**3. Nominal frequency** 22.5792MHz

4. Absolute maximum ratings

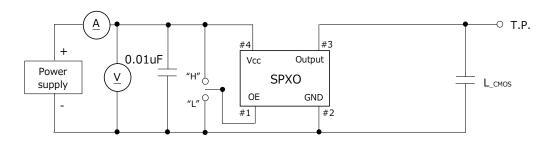
Item	Symbol	Rating	Unit
Supply voltage	Vcc	-0.3 ∼ +4.5	V
Storage temperature range	T_stg	-40 ∼ +85	$^{\circ}$

# 5. Electrical characteristics

Item	Symbol	Limits			Unit Cor		dition	
Item	Syllibol	min.	typ.	max.	Offic	Conc	iidon	
Total frequency tolerance	F_tol	-30	-	+30	ppm	+3.3±0.3V	-40∼+85℃	
Operating temperature range	T_use	-40	-	+85	$\mathbb{C}$	+3.3±0.3∀	-	
Supply voltage	Vcc	+3.0	+3.3	+3.6	V	ı	-40∼+85℃	
Current consumption (No load)	Icc	-	-	2.4	mA	_ - -		
Standby current	I std	-	-	0.01	mA			
(#1 Pin : "L" level)	_							
Symmetry (Duty cycle)	SYM	45	50	55	%			
0 level voltage	Vol	-	-	Vcc×0.1	V			
1 level voltage	Vон	Vcc×0.9	-	-	V	+3.3V	+25±3℃	
Rise & Fall time	tr / tf	-	-	3	ns	±3.5¥	+23±3 C	
Load condition	L_cmos	-	-	15	pF			
0 level input voltage	VIL	-	-	Vcc×0.3	V			
1 level input voltage	VIH	Vcc×0.7	-	-	V			
Output disable time	tPLZ	-	-	200	ns			
Output enable time	tPZL	-	-	2	ms			

Measurement circuit and output wave form is refer to Fig.1. and Fig.2.

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	1 / 10

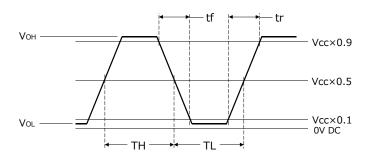


Function

#1 Input	#3 Output condition
Н	Oscillation out
L	High Z

\*L\_cmos : Total fixture and probe capacitance (Refer to Electric characteristics)

Fig.1 Measurement circuit



SYM=  $TH / (TH + TL) \times 100(\%)$ 

Fig.2 Output wave Form

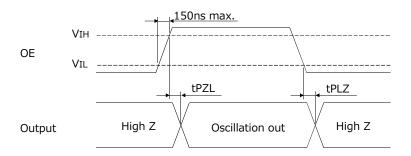
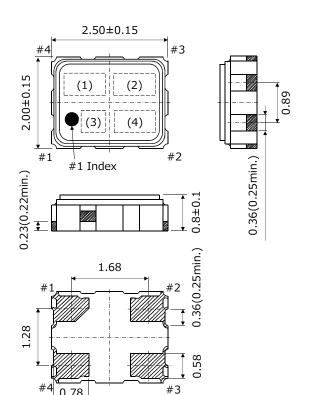


Fig.3 Input output condition

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	2 / 10

# 6. Dimensions and Marking

### Dimensions



Pin connections

Pin No.	Connection
#1	OE(Output enable)
#2	GND
#3	Output
#4	Vcc

Unit: mm

Dimensional tolerance :  $\pm 0.1$ (Unless otherwise noted)

#### 6.2 Marking

- (1) Model code SXF
- (2) Frequency ex.) 22.5792MHz  $\rightarrow$ 22.5
- (3) Logo (4) Lot No.
- D ex.)  $2023/01/01 \rightarrow$ 301

Year : The last digit of the year

Week: We gave the sequence of week numbers 01(first week) for production date.

There are starting from 1st of Jan. However, add '0' figure to the first week during the nine weeks.

The week means are from Sunday to Saturday.

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	3 / 10

### 7. Mechanical characteristics

### 7.1 Shock

# 7.1.1 Mounting drop

A soldered and mounted FR-4 board with thickness of 1.6mm is attached to 100g of aluminum material, and 10cycles of X, Y and Z axis directions (6directions) are dropped on the concrete from height of 150cm. The component shall satisfy requirement of frequency change before and after is within ±8ppm.

### 7.1.2 Acceleration

6ms/1000m/s<sup>2</sup> to X, Y and Z axes (6directions), 10times.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

### 7.2 Vibration

Vibration frequency  $10\sim2000$ Hz, amplitude 1.5mm ( $10\sim55$ Hz), acceleration 200m/s² ( $55\sim2000$ Hz), 2h in X, Y and Z direction with 20min period.

The component shall satisfy requirement of frequency change before and after is within ±8ppm. No visible damage.

### 7.3 Sealing tightness

Leak Rate 1.0x10<sup>-9</sup> Pa·m<sup>3</sup>/s max. measured by Helium leak detector.

### 7.4 Solderability

Rosin flux and immerse in soldering bath at  $+245\pm5\%$  for  $3\pm0.5s$ , and 90% or more of the terminal area is new. It must be covered with solder.

# 7.5 Resistance to soldering heat (Reflow)

When the reflow profile in section 10.1 is measured after 3times, after returning to room temperature (2h intervals) and leaving it for 24 or 48h.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

## 8. Environment characteristics

# 8.1 Humidity

+60±2℃, 90~95% R.H., Duration of 240h.

Back to the room temperature first, then in 24h, be checked.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

# 8.2 Storage in low temperature

-40±2℃, Duration of 240h.

Back to the room temperature first, then in 24h, the component shall be checked.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

## 8.3 Storage in high temperature

+85±2℃, Duration of 240h.

Back to the room temperature first, then in 24h, the component shall be checked.

The component shall satisfy requirement of frequency change before and after is within ±8ppm. No visible damage.

### 8.4 Temperature cycles

-40°C (30min)  $\leftrightarrow$  +85°C (30min) shift time 2~3min, 200cycles.

Back to the room temperature first, then in 24h, the component shall be checked.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

# 8.5 High temperature operation

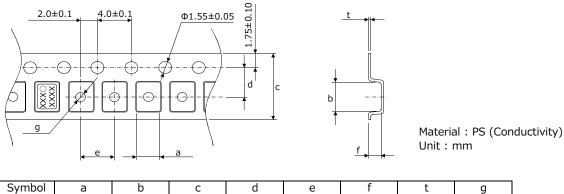
+85±2°C, maximum Vcc, Duration of 240h.

Back to the room temperature first, then in 24h, the component shall be checked.

The component shall satisfy requirement of frequency change before and after is within  $\pm 8$ ppm. No visible damage.

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	4 / 10

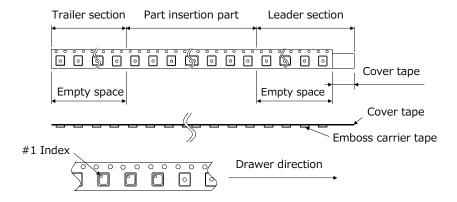
# **9. Taping and Packing**9.1 Emboss carrier tape specifications



#### 2.8 8.0 3.50 4.0 1.15 0.30 2.3 Ф1.05 Size ±0.1 ±0.1 ±0.2 ±0.05 ±0.1 ±0.10 ±0.05 ±0.05

#### 9.2 Joint of tape

Emboss carrier tape and cover tape should not be jointed.



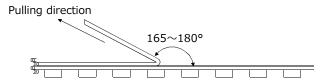
#### 9.3 Taping dimension

Taping unitension	l	
	Cover tape	The length of cover tape in the leader is more than 350mm including
		empty space area.
	Emboss carrier tape	After all products were packaged, must remain more than 10pieces or 150mm empty space area, which should be sealed
	•	by cover tape.
	Cover tape	The empty space area which are sealed by cover tape must remain
Trailer section	Emboss carrier	more than 350mm.
	tape	

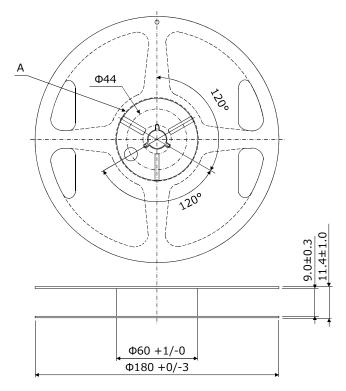
TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	5 / 10

# 9.4

Peeling strength of cover tape The peeling strength of cover tape pulls and keep to angle  $165{\sim}180^\circ$  and make limit  $0.1 \sim 0.7 N$  without prescription, when it pulled it with the speed of 300mm/min. (Others conform to JIS C 0806\_1990)

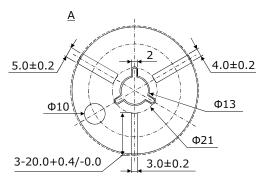


#### 9.5 Reel specifications



Material: PS (Conductivity)

Unit:mm



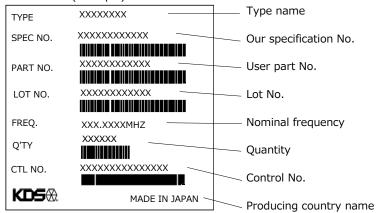
TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	6 / 10

9.6 Storage condition

Temperature: +40°C max. Relative humidity: 80% max.

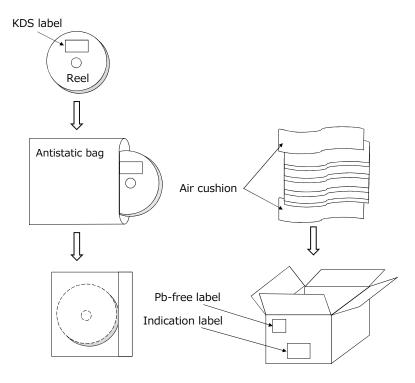
- 9.7 Standard packing quantity 3000pcs. / reel
- 9.8 Label Label is following information. Printing label at each reel.

# KDS label (Example)



## Pb-free label



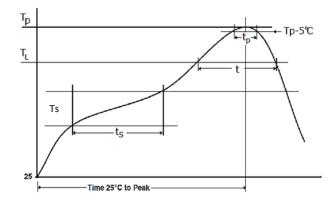


The product is packed up with the method which does not break in the handling by a shipping agent.

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	7 / 10

# 10. Supplement

# 10.1 Reflow condition (Reference)

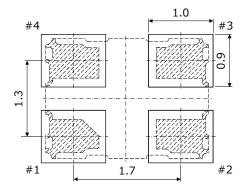


Ts	(℃)	150 ~ 200
ts time	(s)	60 ~ 120
TL	(℃)	217
t time	(s)	$60 \sim 150$
Тр	(℃)	max. 260
tp	(s)	max. 30

# 10.2 Reflow count (Reference)

Please stay with our proposed reflow condition and do then soldering 2times max.

# 10.3 Land pattern layout (Reference)



\_\_\_\_ Land pattern

Unit: mm

# 10.4 Mounting

This component is designed for automatic insertion.

However you are requested to do the trial with your insertion machine in order to be sure of proper operation and no damage of component.

Please pay attention to board warp which may damage the component and cause soldering process. Please mount so that the metalize side and other electrical conductivity structures

(a main part lid is included ) of the base side do not contact electrically.

TITLE DSO221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	8 / 10

# 10.5 Cleaning

Cleaning liquid which corrodes Nickel shall not be used.

It may cause the problem on the surface color marking etc.

Ultrasonic cleaning is possible however you are requested to check on your board.

Because we only checked as single unit.

# 10.6 Handling

This product is designed to withstand Drop and Vibration, however, the crystal blank might be broken. So if excess force is given, please check the characteristics before use.

This product has C-MOS circuit inside.

Please pay attention to latch-up, static-electricity as same handling as other C-MOS devices.

# 10.7 By-pass capacitor

It has no by-pass capacitor integrated.

We recommend you to use capacitor (like ceramic chip capacitor) 0.01µF in-between Vcc and GND.

### 10.8 Storage

Please keep away from high temperature and high humidity, which may cause put solder ability. No direct Sunlight. No dew as well.

# 10.9 Thrust an ultrasonic cleaning

Because It use a small, thin crystal piece depending on a condition, the inside does resonance, and there is fear to cause the non-oscillation. When it's the worst, it may be destroyed. About the ultrasonic cleaning, it is use in the implementation of your company is in a state and confirming a thing without the influence in the appearance and a characteristic beforehand.

### 10.10 Point out supersonic wave welding

It can't recommend implementation by the supersonic wave welding and the processing so that the vibration excessive inside of the crystal oscillator propagates, and there is a threat that it cause characteristic deterioration and the non-oscillation.

# 10.11 RoHS compliance

Following material restricted by RoHS(2011/65/EU,(EU)2015/863) is not included or used.

TITLE DS0221SXF TYPE CRYSTAL OSCILLATOR SPECIFICATION	Remark		
Date	Spec.No.	Rev.	Page
2023/06/19	7FE02257A0C	-	9 / 10

# 2023-0385 REVISION RECORD

Rev.No.	Date	Reason	Contents	Approved	Checked	Drawn
-	2023/06/19	-	The first edition	Y.Momoo	Y.Maeda	S.Yamamoto
		<u> </u>				